

Vishay High Power Products

Passivated Assembled Circuit Elements, 25 A



PACE-PAK (D-19)

PRODUCT SUMMARY	
lo	25 A

FEATURES

- · Glass passivated junctions for greater reliability
- Electrically isolated base plate
- Available up to 1200 V_{RRM}/V_{DRM}
- High dynamic characteristics
- Wide choice of circuit configurations
- Simplified mechanical design and assembly
- UL E78996 approved 😱
- Compliant to RoHS directive 2002/95/EC

DESCRIPTION

The P100 series of integrated power circuits consists of power thyristors and power diodes configured in a single package. With its isolating base plate, mechanical designs are greatly simplified giving advantages of cost reduction and reduced size.

Applications include power supplies, control circuits and battery chargers.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _O	85 °C	25	А		
I _{TSM} , 50 Hz		357	А		
I _{FSM}	60 Hz	375	~		
l ² t	50 Hz	50 Hz 637			
	60 Hz	580	A ² s		
l²√t		6365	A²√s		
V _{RRM}	Range	400 to 1200	V		
V _{ISOL}		2500	V		
TJ		- 40 to 125	°C		
T _{Stg}		- 40 10 125	U		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK REVERSE AND PEAK OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J MAXIMUM mA		
P101, P121, P131	400	500			
P102, P122, P132	600	700			
P103, P123, P133	800	900	10		
P104, P124, P134	1000	1100			
P105, P125, P135	1200	1300			



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ON-STATE CONDUCTIO	N					
PARAMETER	SYMBOL		TEST CON	DITIONS	VALUES	UNITS
Maximum DC output current	I	Full bridge			25	А
at case temperature	Ι _Ο	Full bridge			85	°C
		t = 10 ms	No voltage		357	
Maximum peak, one-cycle	I _{TSM} ,	t = 8.3 ms	reapplied		375	^
non-repetitive on-state or forward current	I _{FSM}	t = 10 ms	100 % V _{RRM}		300	A
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	315	
		t = 10 ms	No voltage reapplied		637	A ² s
Maximum I ² t for fusing	l ² t	t = 8.3 ms			580	
		t = 10 ms	100 % V _{RRM} reapplied		450	
		t = 8.3 ms			410	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied $I^2 t$ for time tx = $I^2 \sqrt{t} \cdot \sqrt{tx}$		6365	A²√s	
Maximum value of threshold voltage	V _{T(TO)}	T _J = 125 °C		0.82	V	
Maximum level value of on-state slope resistance	r _{t1}	T _J = 125 °C,	T_J = 125 °C, average power = $V_{T(TO)} \times I_{T(AV)} + r_t + (I_{T(RMS)})^2$		12	mΩ
Maximum on-state voltage drop	V _{TM}	$I_{TM} = \pi \times I_{T(A)}$	N)	T 05 %C	1.35	V
Maximum forward voltage drop	V _{FM}	$T_J = 25 \text{ °C}$		1.35	V	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	T_J = 125 °C from 0.67 V _{DRM} I _{TM} = π x I _{T(AV)} , I _q = 500 mA, t _r < 0.5 μs, t _p > 6 μs		200	A/µs	
Maximum holding current	Ι _Η	$T_J = 25$ °C anode supply = 6 V, resistive load, gate open		130		
Maximum latching current	١L	$T_J = 25 \text{ °C}$ anode supply = 6 V, resistive load		250	mA	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T_J = 125 °C, exponential to 0.67 V _{DRM} gate open	200	V/µs
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM} , I _{DRM}	T _J = 125 °C, gate open circuit	10	mA
Maximum peak reverse leakage current	I _{RRM}	T _J = 25 °C	100	μA
RMS isolation voltage	V _{ISOL}	50 Hz, circuit to base, all terminals shorted, T_J = 25 °C, t = 1 s	2500	V



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TRIGGERING					
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}			8	W
Maximum average gate power	P _{G(AV)}			2	vv
Maximum peak gate current	I _{GM}			2	A
Maximum peak negative gate voltage	-V _{GM}			10	V
Maximum gate voltage required to trigger	V _{GT}	T _J = - 40 °C		3	V
		T _J = 25 °C		2	
		T _J = 125 °C	Anode supply =	1	
	I _{GT}	T _J = - 40 °C	6 V resistive load	90	
Maximum gate current required to trigger		T _J = 25 °C		60	
		T _J = 125 °C		35	
Maximum gate voltage that will not trigger	V _{GD}	$- T_{\rm J} = 125 ^{\circ}{\rm C}, \text{rated V}_{\rm DRM} \text{ applied} \qquad \qquad$		0.2	V
Maximum gate current that will not trigger	I _{GD}			mA	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation	2.24	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.10	K/W
Mounting torque, base to heatsink ⁽¹⁾			4	Nm
Approvimate weight			58	g
Approximate weight			2.0	OZ.

Note

⁽¹⁾ A mounting compund is recommended and the torque should be checked after a period of 3 hours to allow for the spread of the compound

CIRCUIT TYPE AND CODI				
	CIRCUIT "0"	CIRCUIT "2"	CIRCUIT "3"	
Terminal positions	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	AC1 G1 - AC2 G2 +	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	
Schematic diagram	(-)	(-) $(-)$	$G3 \circ G1$ AC1 $AC2 \circ$ (-) $G4 G2$ (+)	
	Single phase hybrid bridge common cathode	Single phase hybrid bridge doubler	Single phase all SCR bridge	
Basic series	P10.	P12.	P13.	
With voltage suppression	P10.K	P12.K	P13.K	
With freewheeling diode	P10.W	-	-	
With both voltage suppression and freewheeling diode	P10.KW	-	-	

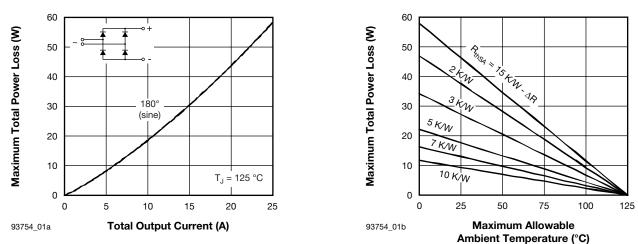
Note

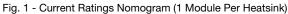
⁽¹⁾ To complete code refer to Voltage Ratings table, i.e.: For 600 V P10.W complete code is P102W

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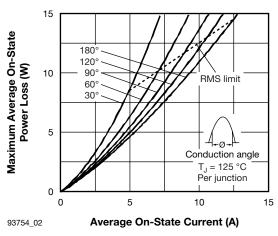


Fig. 2 - On-State Power Loss Characteristics

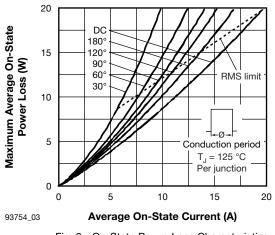
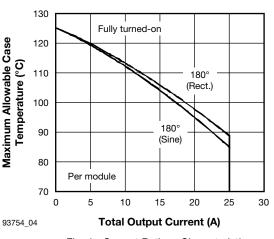
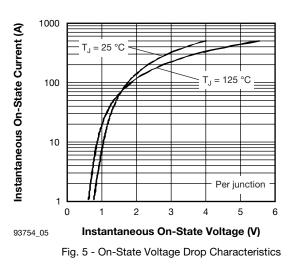


Fig. 3 - On-State Power Loss Characteristics





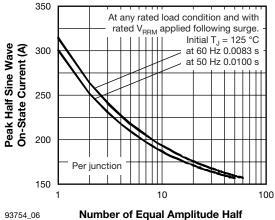




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Number of Equal Amplitude Half Cycle Current Pulses (N) Fig. 6 - Maximum Non-Repetitive Surge Current

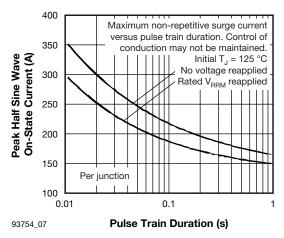
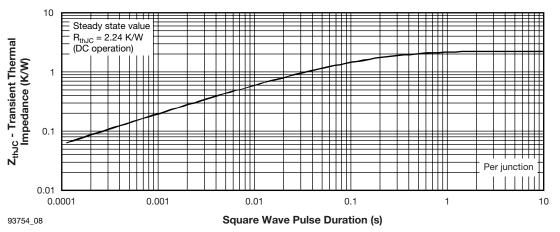
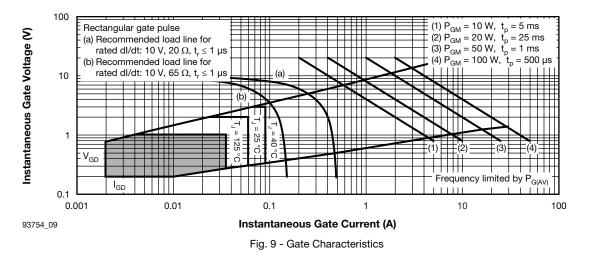


Fig. 7 - Maximum Non-Repetitive Surge Current







LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95335			



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